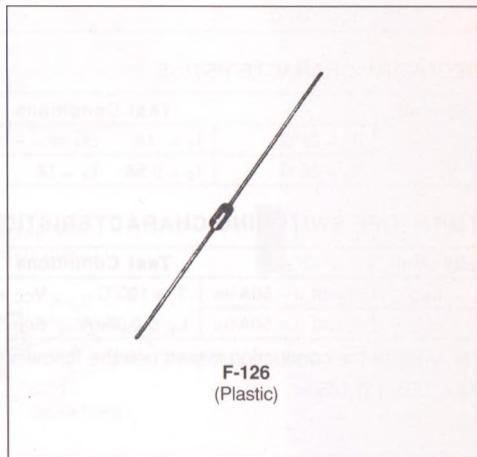


FAST RECOVERY RECTIFIER DIODES

FAST RECOVERY RECTIFIER

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING


SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTORS CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value		Unit
$I_{F(Repetitive)}$	Repetitive Peak Forward Current	$t_p \leq 10\mu s$	30	A
$I_{F(AV)}$	Average Forward Current *	$T_a = 70^\circ C$ $\delta = 0.5$	1	A
I_{FSM}	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	30	A
P	Power Dissipation *	$T_a = 70^\circ C$	1.33	W
T_{stg} T_j	Storage and Junction Temperature Range	- 40 to + 150		°C

Symbol	Parameter	BYT 01-			Unit
		200	300	400	
V_{RRM}	Repetitive Peak Reverse Voltage	200	300	400	V
V_{RSM}	Non Repetitive Peak Reverse Voltage	220	330	440	V

THERMAL RESISTANCE

Symbol	Parameter	Value		Unit
$R_{th(j-a)}$	Junction-ambient *	60		°C/W

* On infinite heatsink with 10mm lead length.

ELECTRICAL CHARACTERISTICS**STATIC CHARACTERISTICS**

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
I _R	T _j = 25°C	V _R = V _{RRM}				20	μA
	T _j = 100°C					0.5	mA
V _F	T _j = 25°C	I _F = 1A				1.5	V
	T _j = 100°C					1.4	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t _{rr}	T _j = 25°C	I _F = 1A	dI _F /dt = - 15A/μs	V _R = 30V		55	ns
	T _j = 25°C	I _F = 0.5A	I _R = 1A	I _{rr} = 0.25A		25	

TURN -OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Min.	Typ.	Max.	Unit	
t _{IRM}	dI _F /dt = - 50A/μs	T _j = 100°C	V _{CC} = 200V	I _F = 1A		35	50	ns
I _{RM}	dI _F /dt = - 50A/μs	L _p ≤ 0.05μA	See figure 12			1.5	2	A

To evaluate the conduction losses use the following equations :

$$V_F = 1.05 + 0.145 I_F$$

$$P = 1.05 \times I_{F(AV)} + 0.145 I_{F(RMS)}^2$$

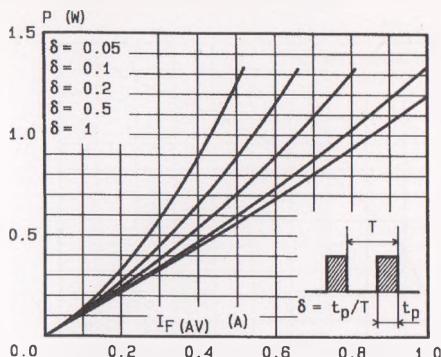


Fig.1 - Maximum average power dissipation versus average forward current.

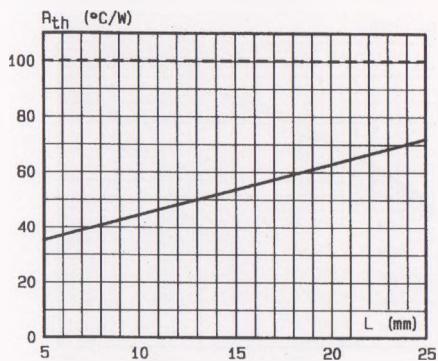


Fig.3 - Thermal resistance versus lead length.

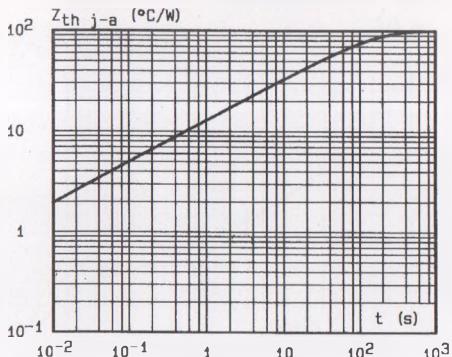


Fig.4 - Transient thermal impedance junction-ambient for mounting n°2 versus pulse duration ($L = 10$ mm).

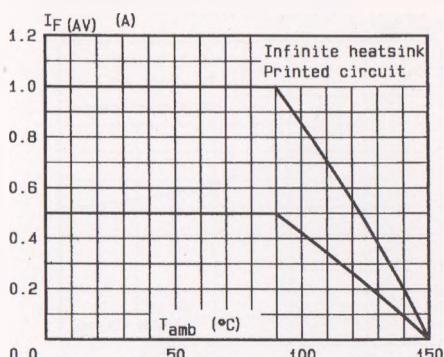


Fig.2 - Average forward current versus ambient temperature.

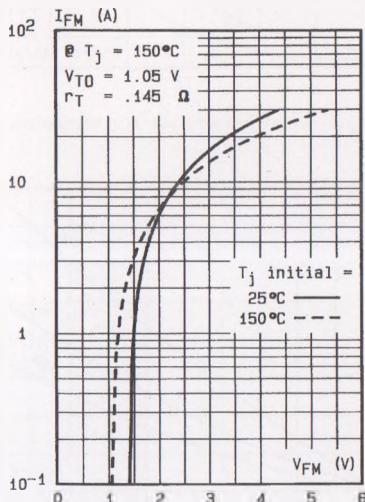
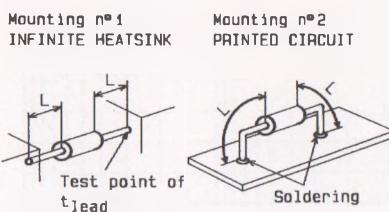


Fig.5 - Peak forward current versus peak forward voltage drop (maximum values).

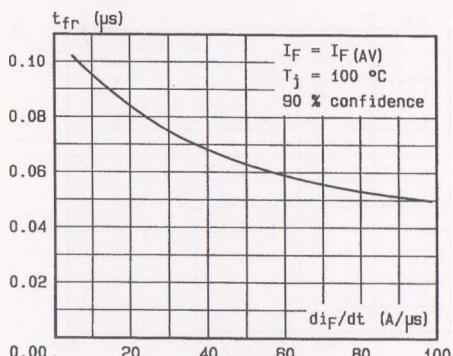
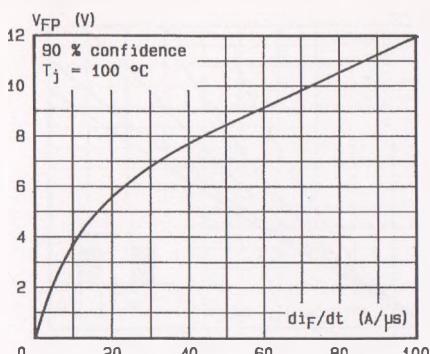
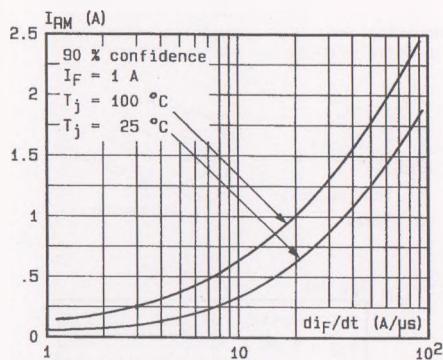
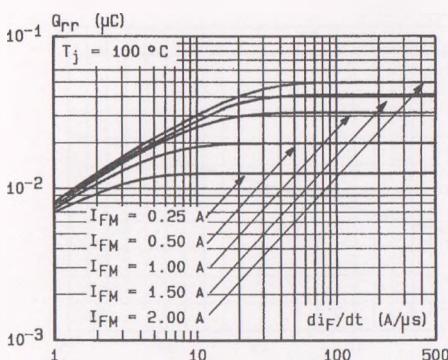
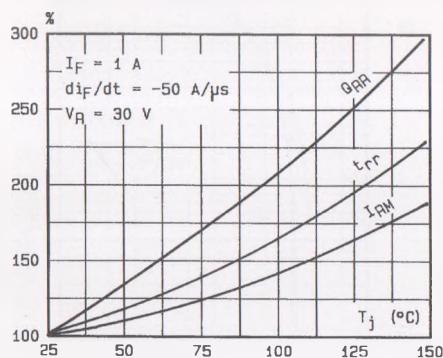
Fig.7 - Recovery time versus di_F/dt .Fig.8 - Peak forward voltage versus di_F/dt .Fig.9 - Peak reverse current versus di_F/dt .Fig.10 - Recovered charge versus di_F/dt (typical values).

Fig.11 - Dynamic parameters versus junction temperature.

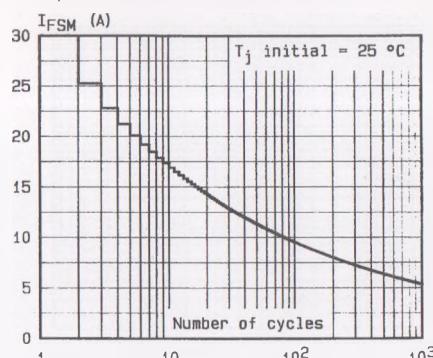


Fig.12 - Non repetitive surge peak current versus number of cycles